



N-Channel and P-Channel Complementary MOSFET

Product Summary

NMOS

V_{DS}	30V
I_D	4A
$R_{DS(ON)}$ (at $V_{GS}=10V$)	35m
$R_{DS(ON)}$ (at $V_{GS}=4.5V$)	55m

PMOS

V_{DS}	-30V
I_D	-3A
$R_{DS(ON)}$ (at $V_{GS}=-10V$)	75m
$R_{DS(ON)}$ (at $V_{GS}=-4.5V$)	110m

General Description

ch Power LV MOSFET technology

Applications

Absolute Maximum Ratings ($T_A=25$



YJU3724A

NMOS Electrical Characteristics (T_J=25 unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =250	30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	
		V _{DS} =30V, V _{GS} =0V, T _J =150	-	-	100	
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ± 20V, V _{DS} =0V	-	-	± 100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =250	1	1.5	2.5	V
Static Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =4A	-	26	35	m
		V _{GS} =4.5V, I _D =3A	-	41	55	
Diode Forward Voltage	V _{SD}	I _S =4A, V _{GS} =0V	-	-	1.2	V
Gate resistance	R _G	f=1MHz	-	2.5	-	
Maximum Body-Diode Continuous Current	I _S		-	-	4	A
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1MHz	-	230	-	pF
Output Capacitance	C _{oss}		-	45	-	
Reverse Transfer Capacitance	C _{rss}		-	35	-	
Switching Parameters						
Total Gate Charge	Q _g	V _{GS} =10V, V _{DS} =15V, I _D =4A	-	6	-	nC
Gate-Source Charge	Q _{gs}		-	1.4	-	
Gate-Drain Charge	Q _{gd}		-	1.2	-	
Reverse Recovery Charge	Q _{rr}	I _F =4A, di/dt=100A/us	-	1.0	-	nC
Reverse Recovery Time	t _{rr}		-	5.5	-	ns
Turn-on Delay Time	t _{D(on)}	V _{GS} =10V, V _{DD} =15V, I _D =4A R _{GEN} =3	-	5	-	ns
Turn-on Rise Time	t _r		-	30	-	
Turn-off Delay Time	t _{D(off)}		-	8	-	
Turn-off fall Time	t _f		-	24	-	

PMOS Electrical Characteristics (T_J=25 unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =-250	-30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	
		V _{DS} =-30V, V _{GS} =0V, T _J =150	-	-	-100	
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ± 20V, V _{DS} =0V	-	-	± 100	nA



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Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250$	-1	-1.5	-2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -3A$	-	58	75	m
		$V_{GS} = -4.5V, I_D = -3A$	-	85	110	
Diode Forward Voltage	V					



NMOS Typical Electrical and Thermal Characteristics Diagrams

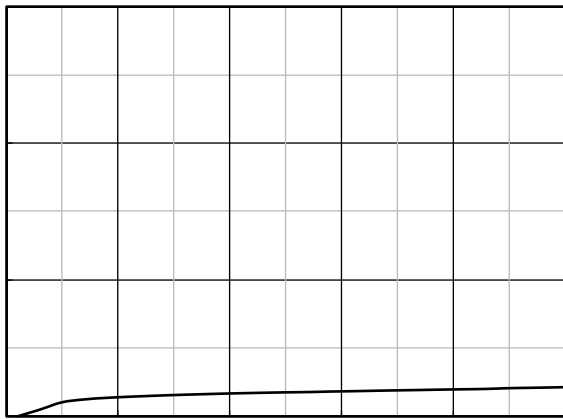


Figure 1. Output Characteristics

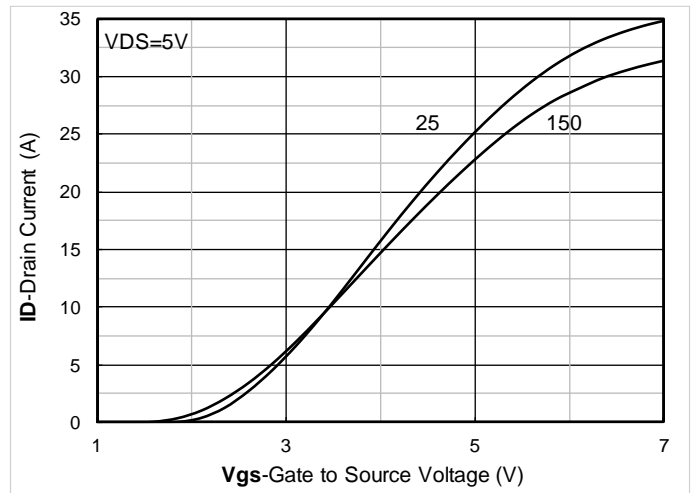


Figure 2. Transfer Characteristics

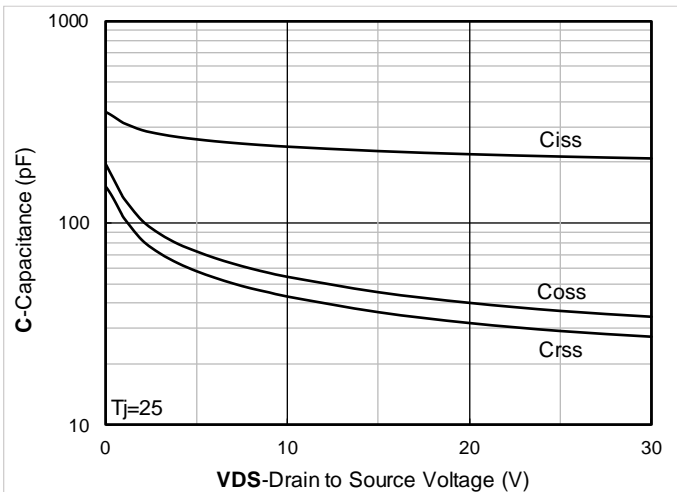


Figure 3. Capacitance Characteristics

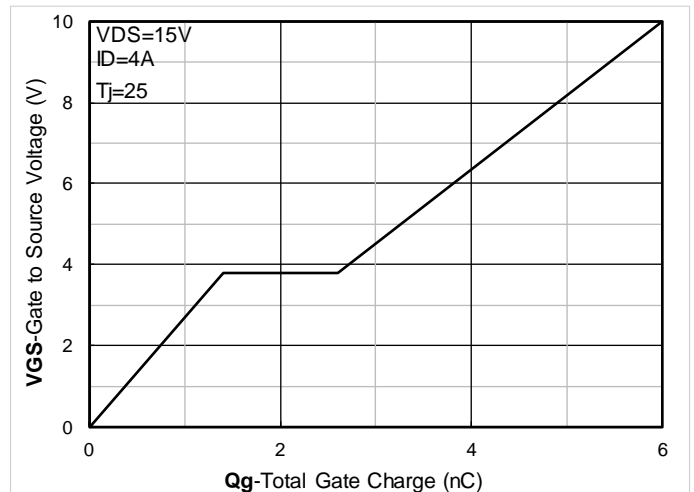


Figure 4. Gate Charge

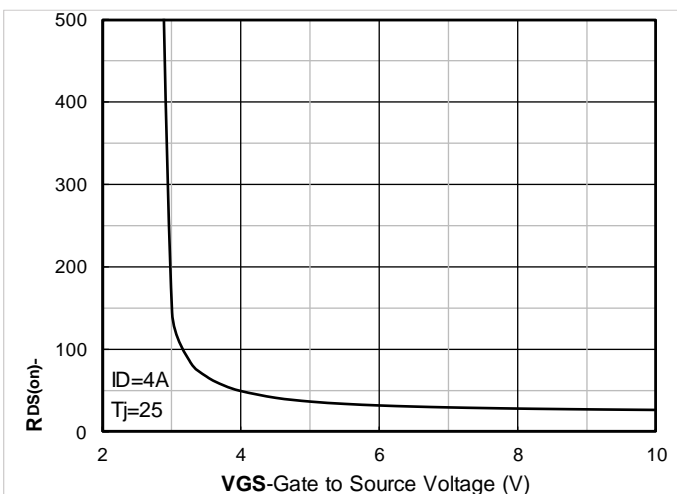


Figure 5. On-Resistance vs Gate to Source Voltage

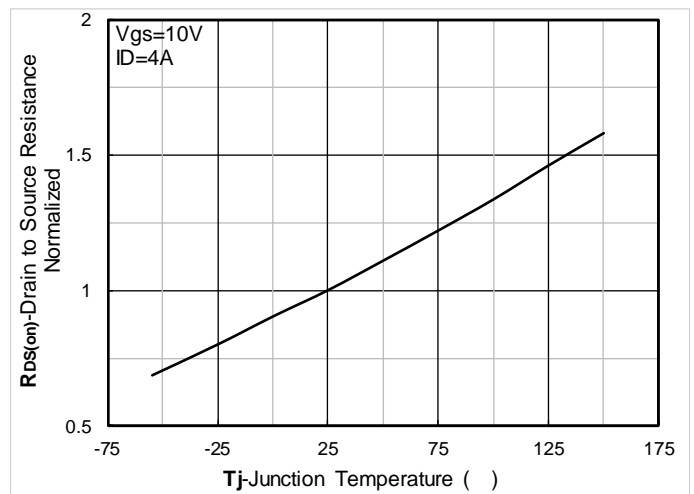


Figure 6. Normalized On-Resistance

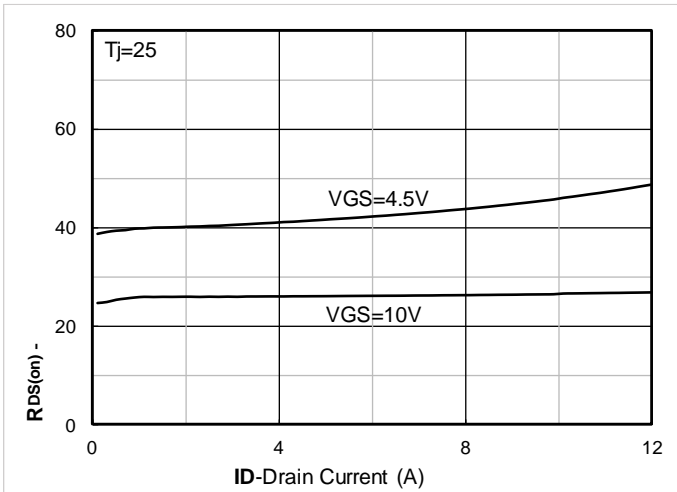


Figure 7. RDS(on) VS Drain Current

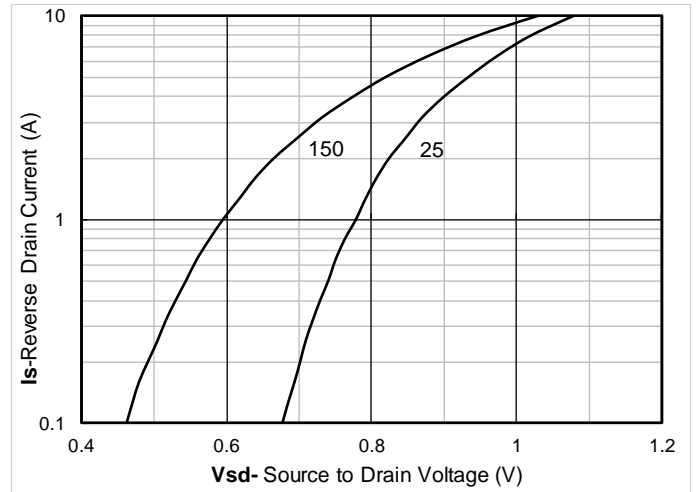


Figure 8. Forward characteristics of reverse diode

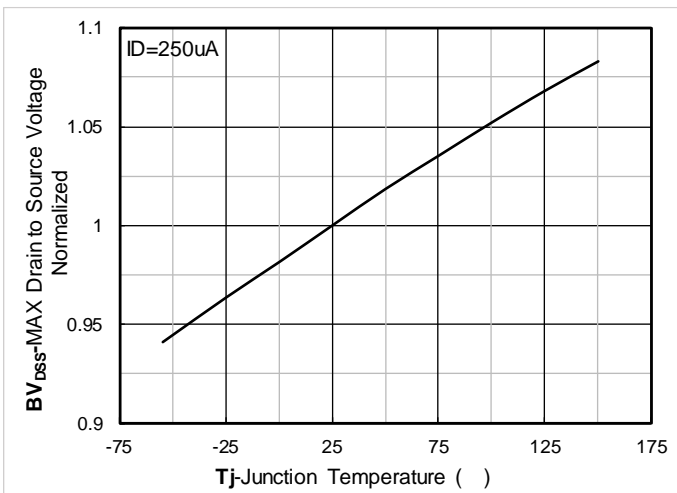


Figure 9. Normalized breakdown voltage

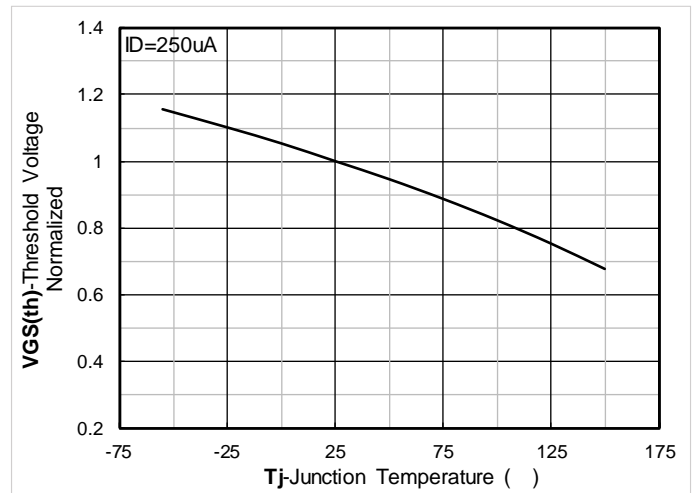


Figure 10. Normalized Threshold voltage

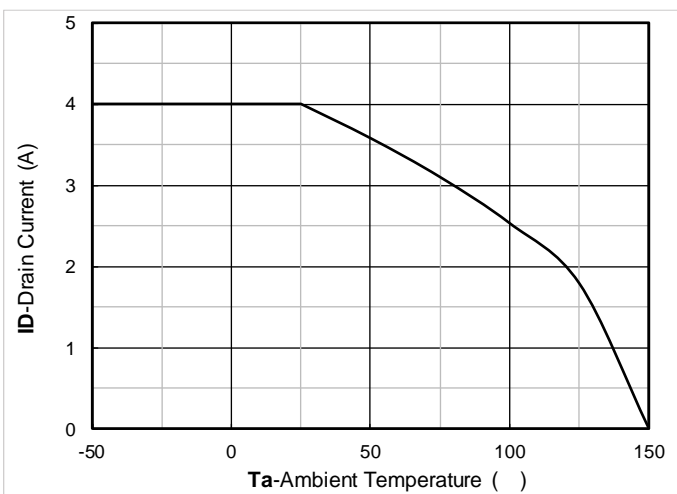


Figure 11. Current dissipation

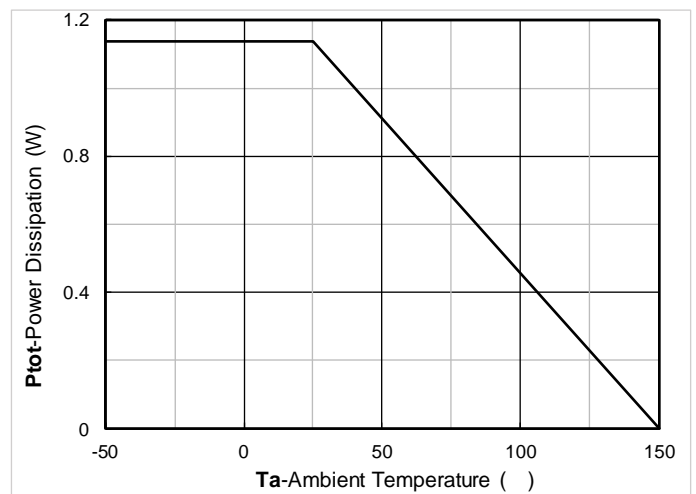


Figure 12. Power dissipation

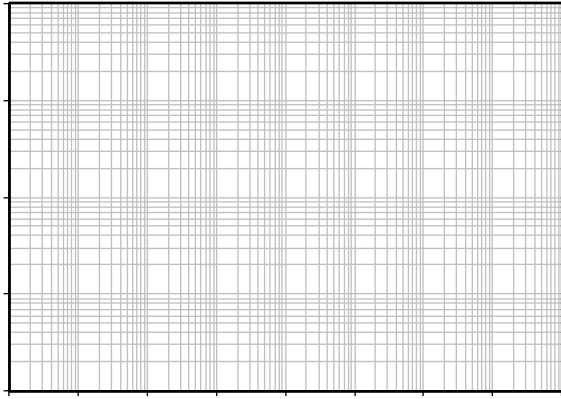


Figure 13. Maximum Transient Thermal Impedance

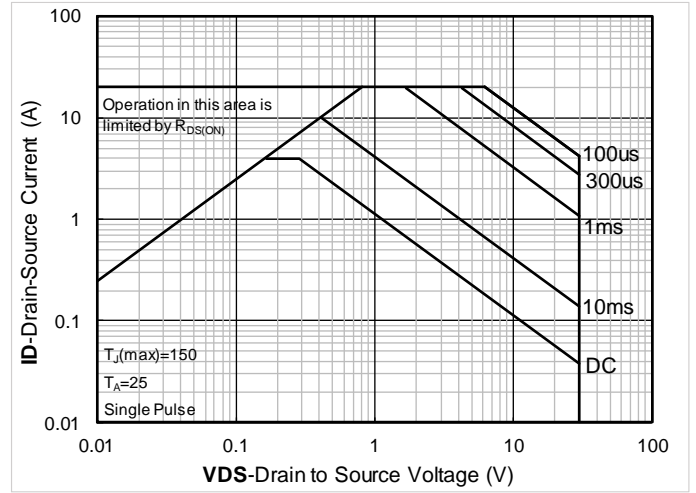


Figure 14. Safe Operation Area

PMOS Typical Electrical and Thermal Characteristics Diagrams

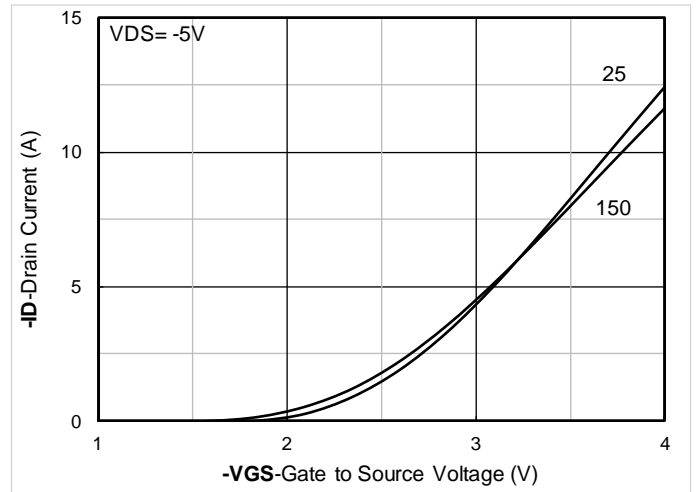


Figure 2. Transfer Characteristics

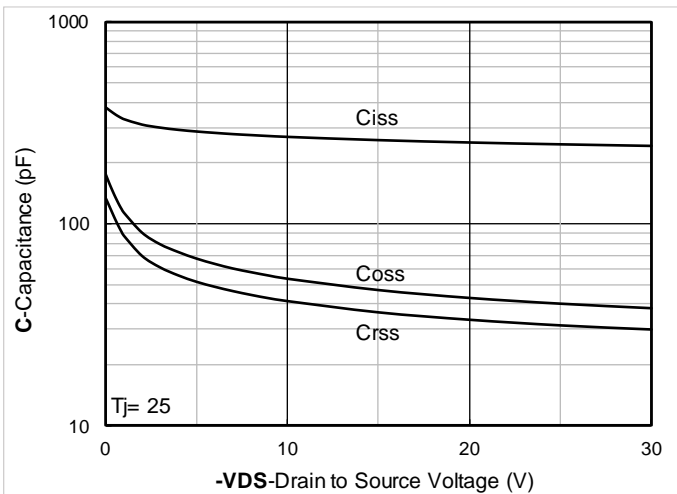


Figure 3. Capacitance Characteristics

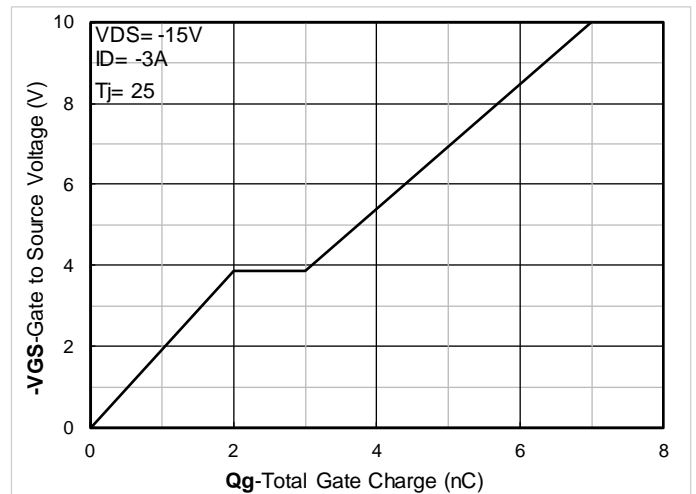


Figure 4. Gate Charge

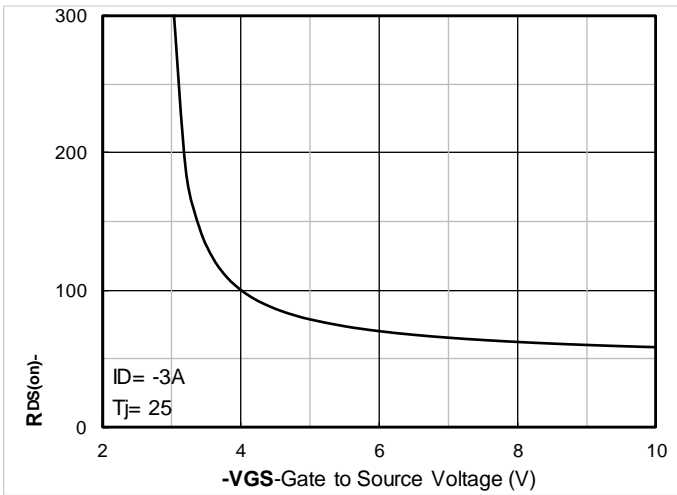


Figure 5. On-Resistance vs Gate to Source Voltage

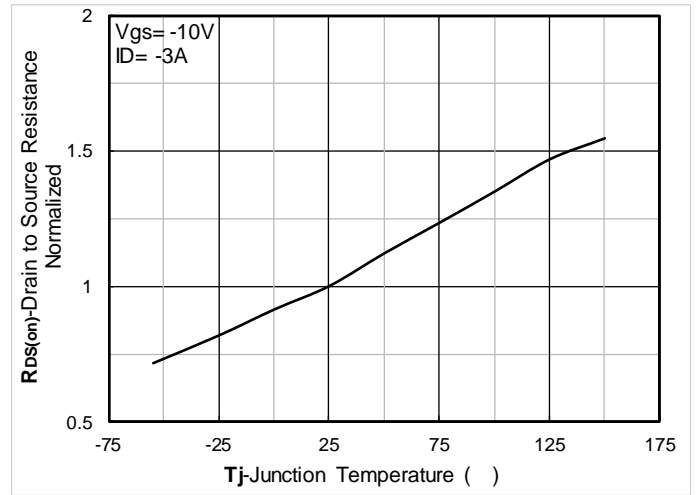


Figure 6. Normalized On-Resistance

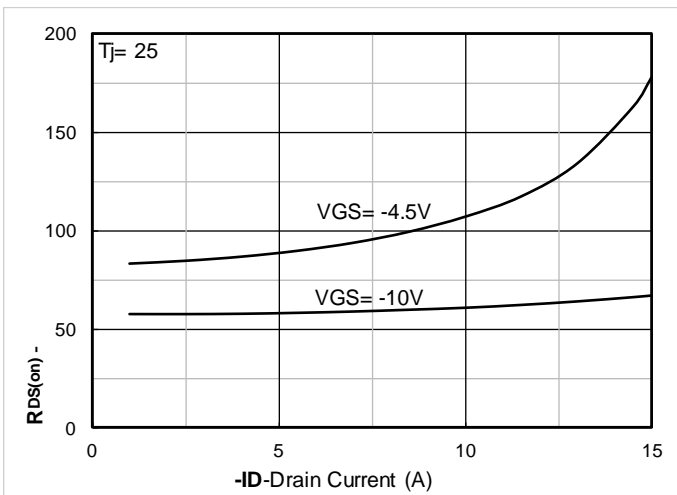


Figure 7. RDS(on) VS Drain Current

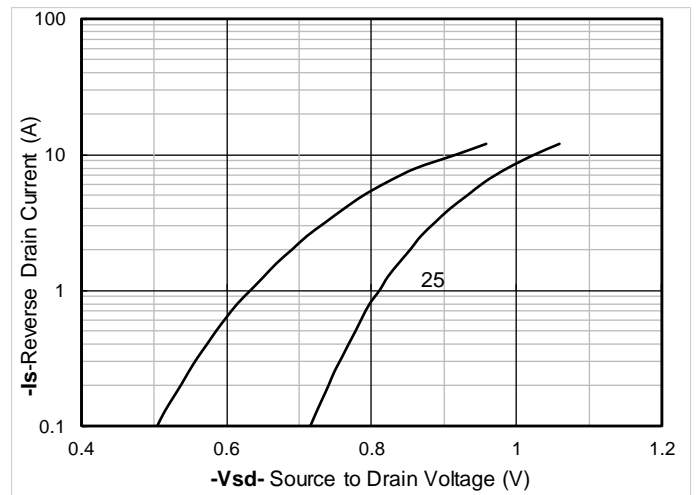


Figure 8. Forward characteristics of reverse diode

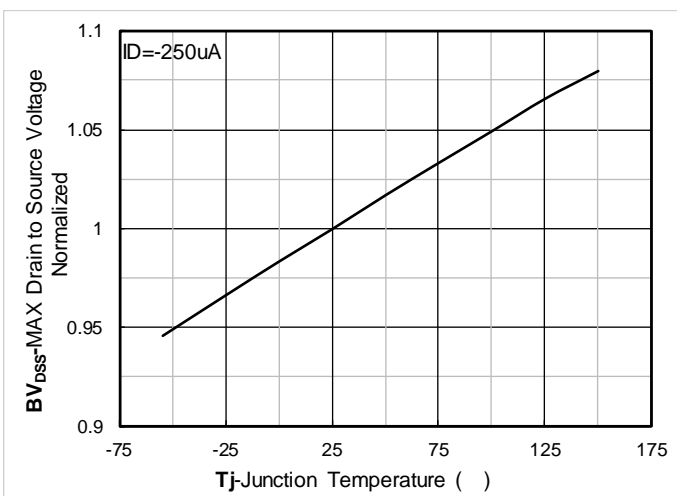


Figure 9. Normalized breakdown voltage

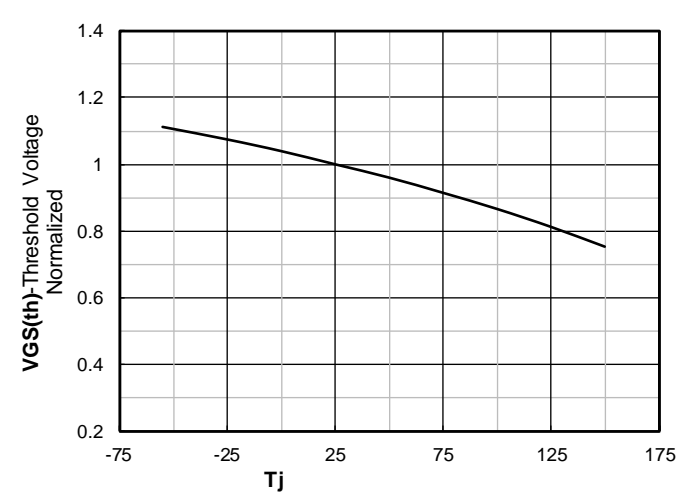


Figure 10. Normalized Threshold voltage

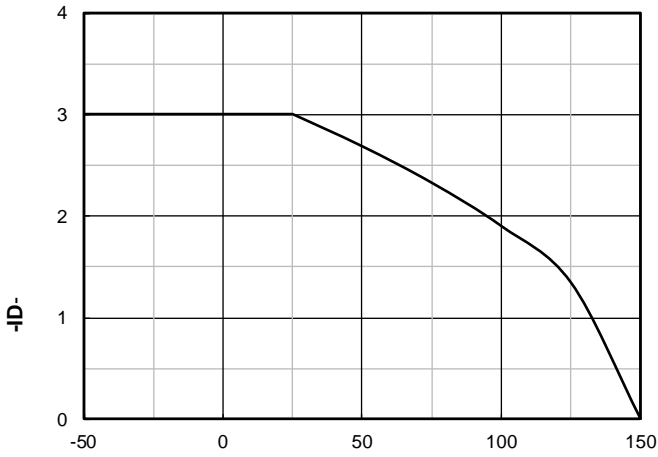


Figure 11. Current dissipation

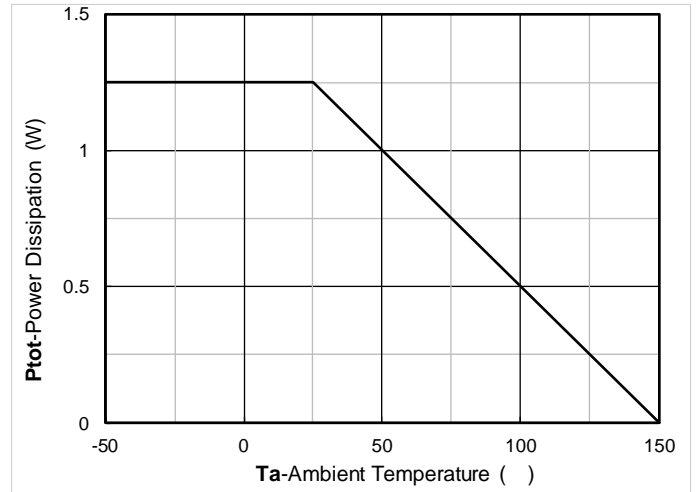


Figure 12. Power dissipation

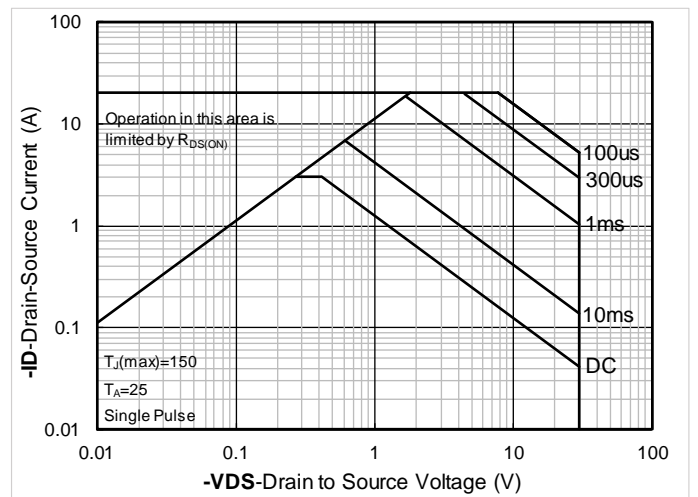


Figure 14. Safe Operation Area

Figure 13. Maximum Transient Thermal Impedance



PDFN3030-8L Package information

TOP VIEW

SIDE VIEW

BOTTOM VIEW

